

Organic Photovoltaics: Overview and Aspects of Theory, Modeling, and Simulation

Sean Shaheen

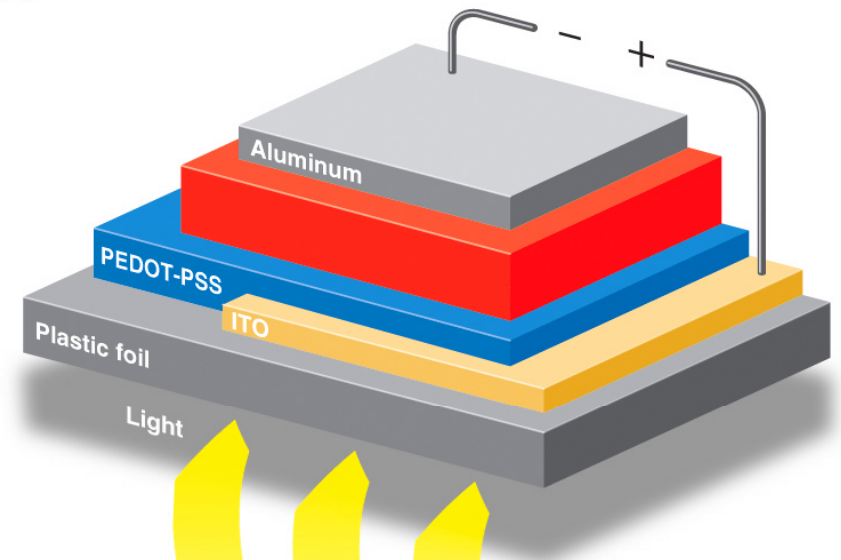
Assoc. Professor
Dept. of Physics and Astronomy
University of Denver



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NATURAL SCIENCES & MATHEMATICS

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**NSF Challenges in PV Science, Technology, and Manufacturing:
The Role of Theory, Modeling, and Simulation**
Purdue University
August 2, 2012

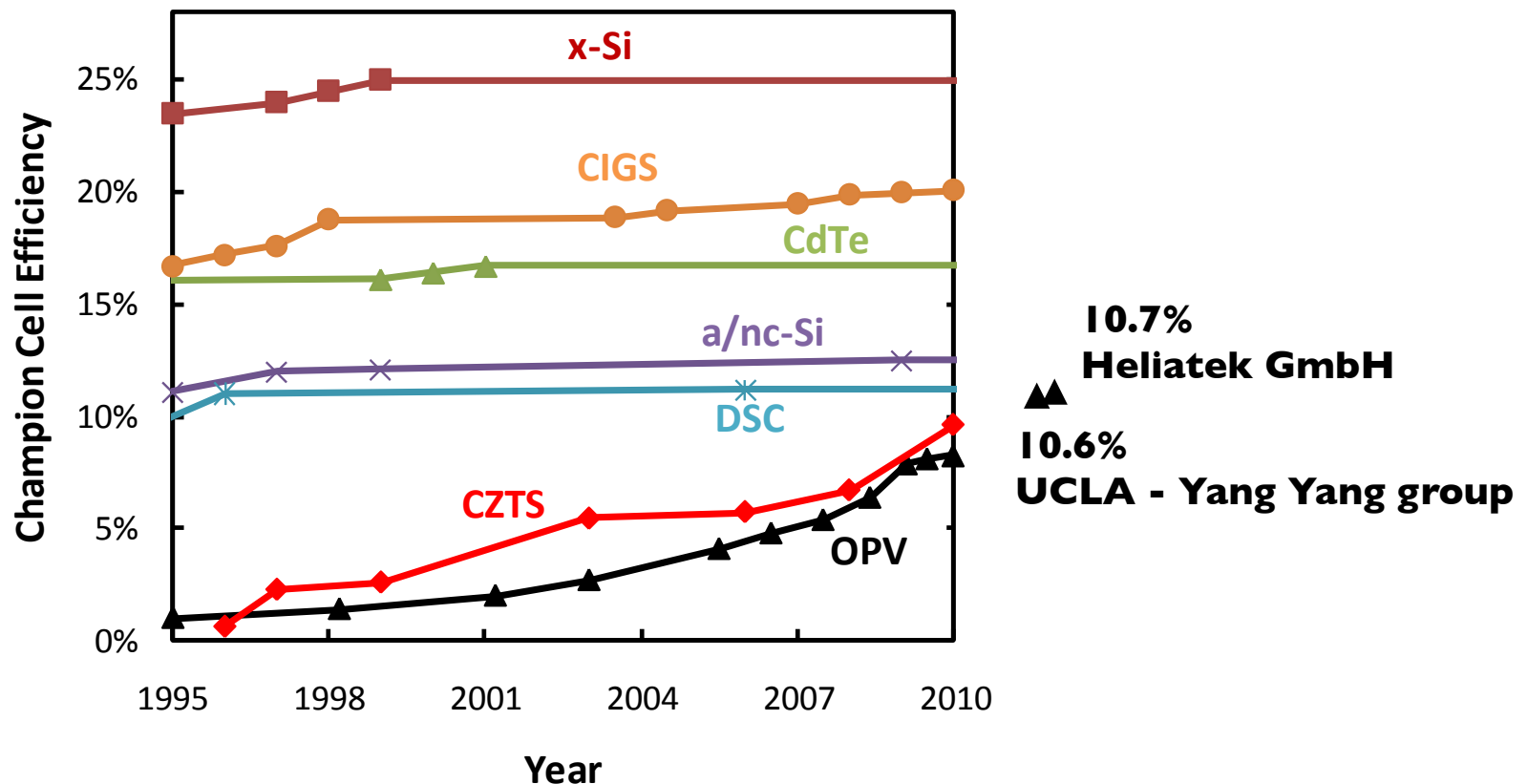
Progress in organic photovoltaic efficiencies

Early days of OPV:

- 1958: first reported organic photovoltaic device (Kearns and Calvin, UC Berkeley)
- 1960's - 70's: early work with tetracene, phthalocyanine, and polyvinylcarbazole
- 1986: two-layer cell from phthalocyanine-perylene (CW Tang)
- 1990's: development of pi-conjugated polymers and fullerenes (Friend, Heeger, others)

Recent progress in efficiencies:

*The evolution of champion cell single-junction efficiency since 1995 for various PV technologies**



*C.A. Wolden, J. Kurtin, J. B. Baxter, I. Repins, S. E. Shaheen, J. T. Torvik, A. Rockett, V. Fthenakis, E. S. Aydil, "Photovoltaic Manufacturing: Present Status and Future Prospects", *Journal of Vacuum Science and Technology A*, **29** (3) 030801 (2011).

Companies working on OPV (partial list)

10.7% efficiency
(tandem device)

heliatek 

Organic based Photovoltaics

<http://www.heliatek.com>

10.1% efficiency
(single junction)

 **MITSUBISHI
CHEMICAL**

<http://www.m-kagaku.co.jp/english/aboutmcc/RC/special/feature1.html>

 **Polyera**

<http://www.polyera.com>

9.1% efficiency
(inverted device)

 **SOLARMER[®]**
Energy, Inc.

<http://www.solarmer.com/>

 **PLEXTRONICS**
Light. Power. Circuitry.™

<http://www.plextronics.com/>



BOSCH

http://www.bosch.com/en/com/innovation/insidebosch/solar_energy_innovation/solar-energy.html



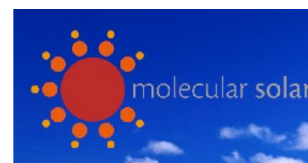
<http://www.basf-futurebusiness.com/en/projects/organic-electronics/organic-photovoltaics.html>

 **Eight19**

<http://www.eight19.com>

 **Solar Press**
Solar Power For Everyone

<http://www.solar-press.com/>



<http://www.molecularsolar.co.uk/>



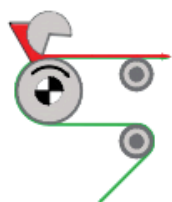
<http://www.ossila.com/>

Industrial manufacturing capability being developed

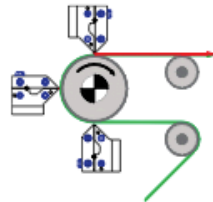
Coating plant for flexible electronics (*Holst Centre*):

<http://www.holstcentre.com/>

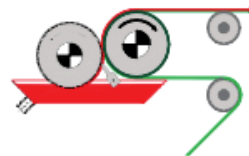
<http://www.coatema.de>



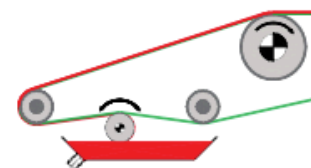
**Commabar
System**



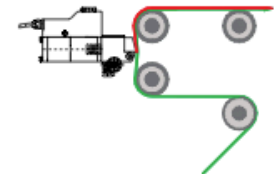
**Slot Die
System**



**Engraved Roller
System**



**Micro Roller
System**



**Hotmelt
System**

Industrial manufacturing capability being developed

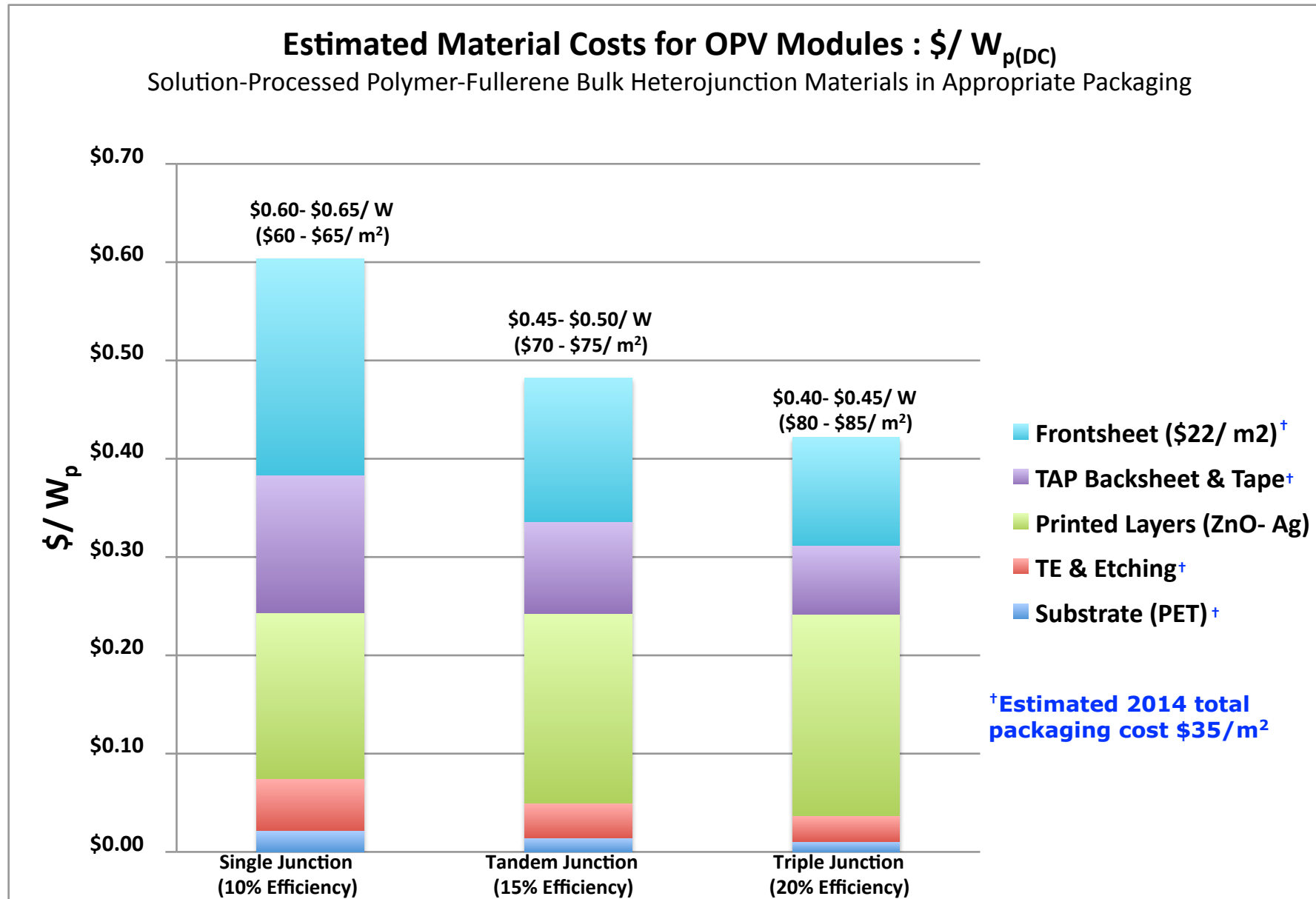
Heliatek, Dresden (Saxony) plant

- roll-to-roll vacuum processing
- 2 - 3 MW in 2012
- new facility with 50 - 75 MW in 2014

<http://www.heliatek.com/>



Preliminary analysis of OPV material costs*

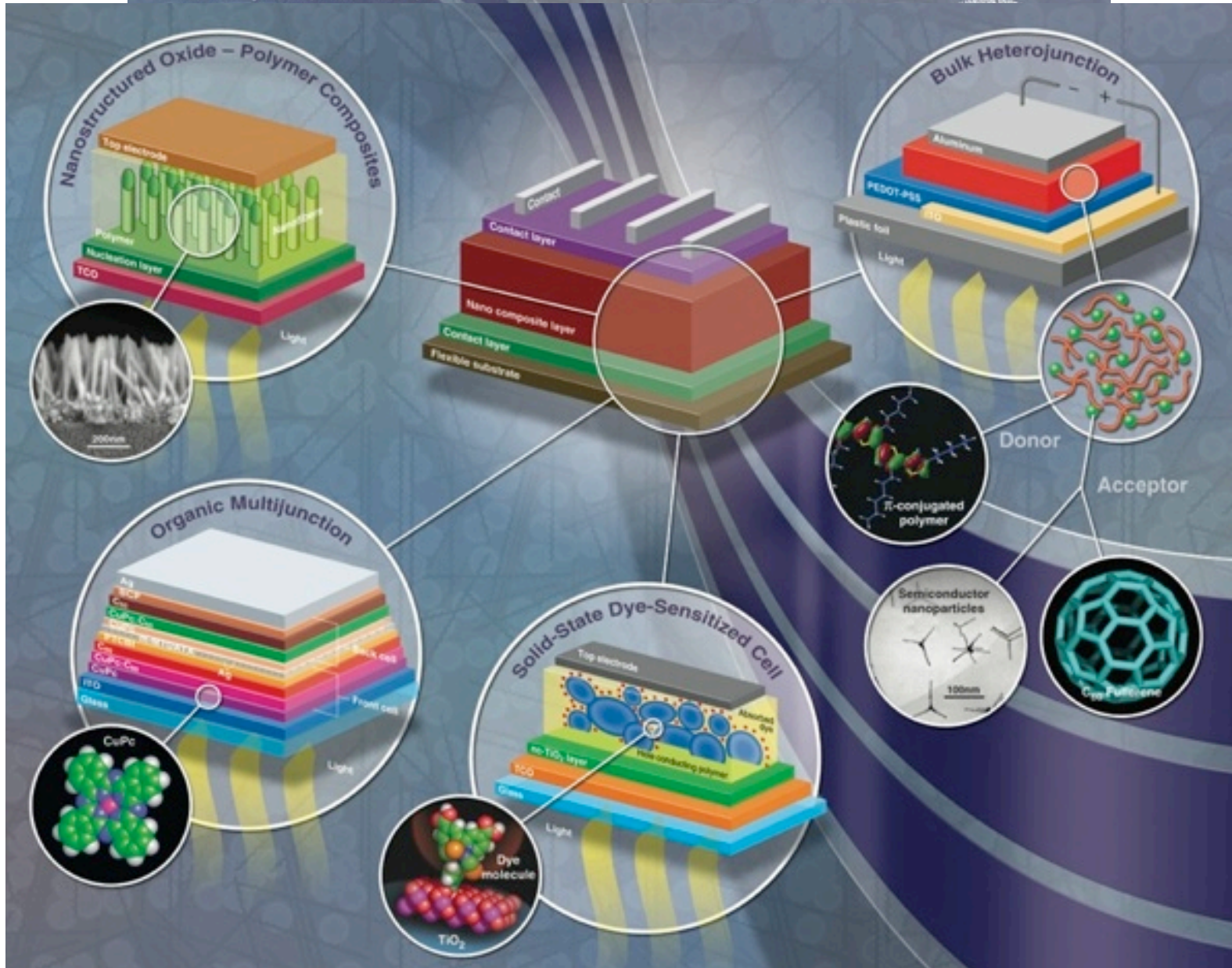


*NREL Energy Analysis team (Michael Woodhouse, Alan Goodrich) and OPV team (Dana Olson, Matthew Reese, David Ginley)

MRS BULLETIN

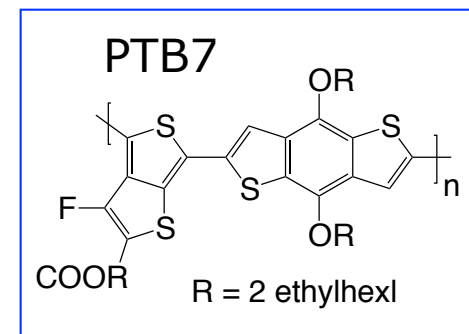
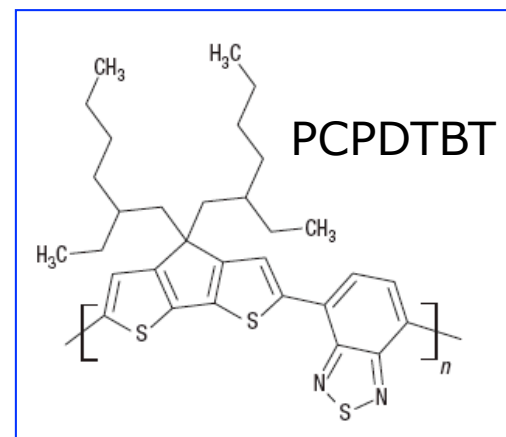
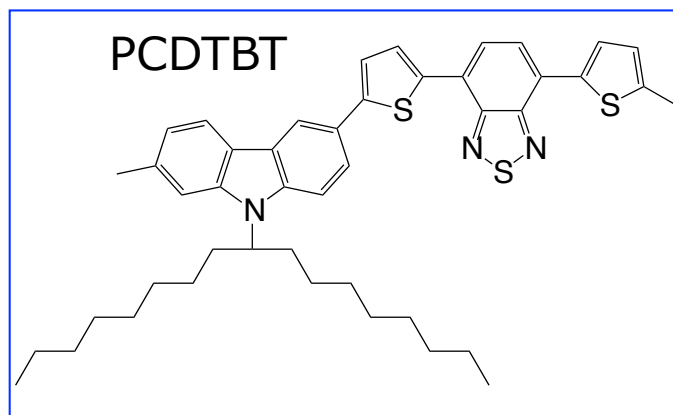
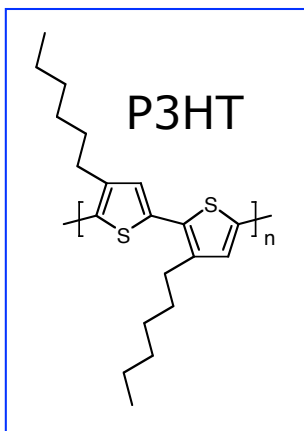
Serving the International
Materials Research Community
A Publication of the Materials Research Society

January 2005, Volume 30, No. 1

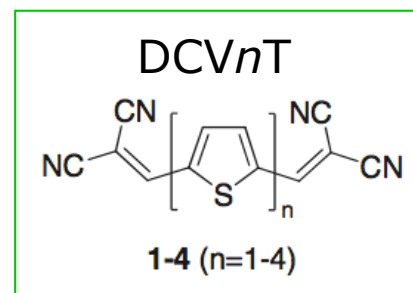
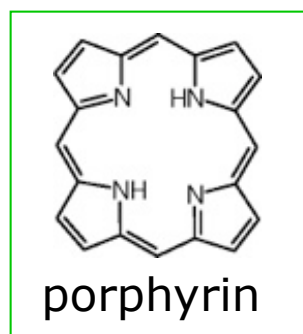
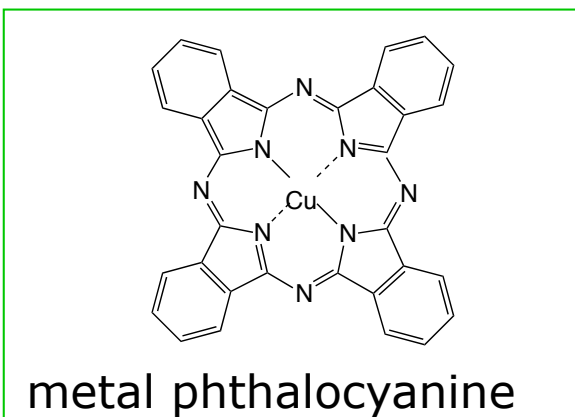


Some typical electron *donor* molecules

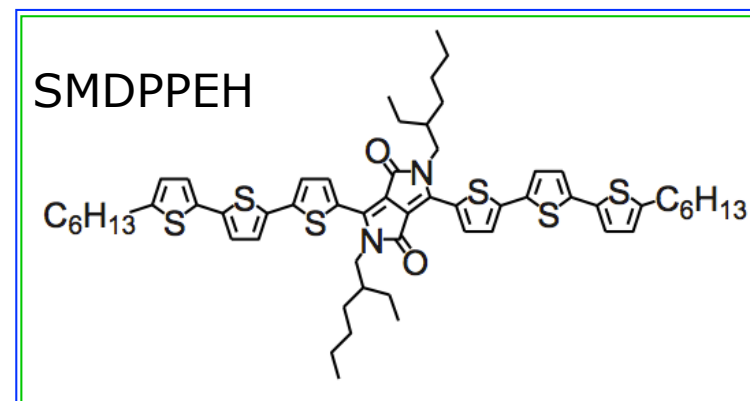
polymers - require solution processing



small molecules - require vacuum deposition

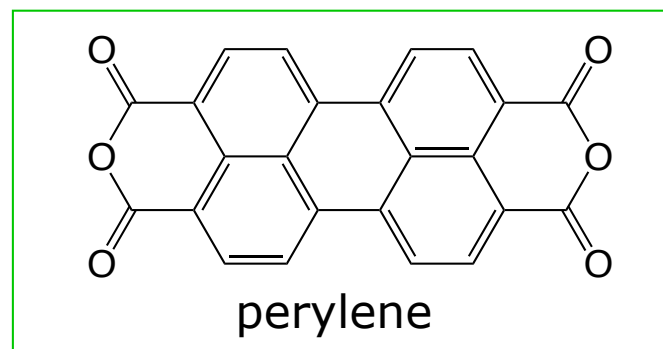
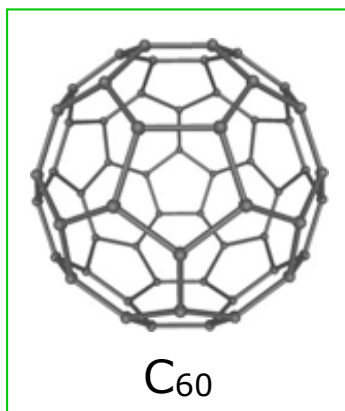


solution processable small molecules

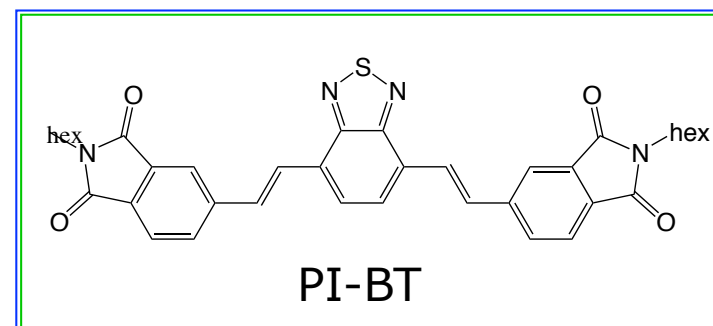
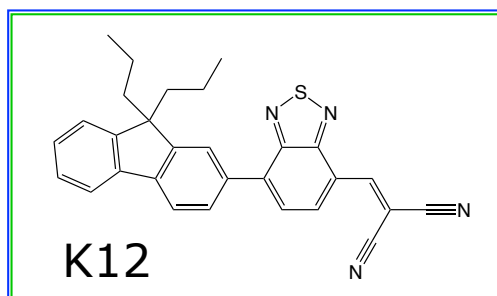
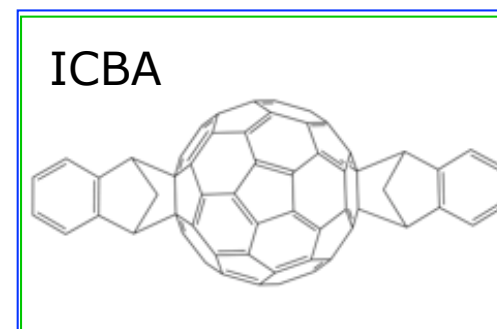
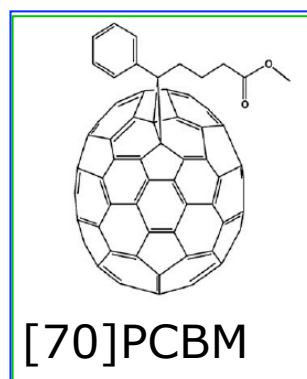
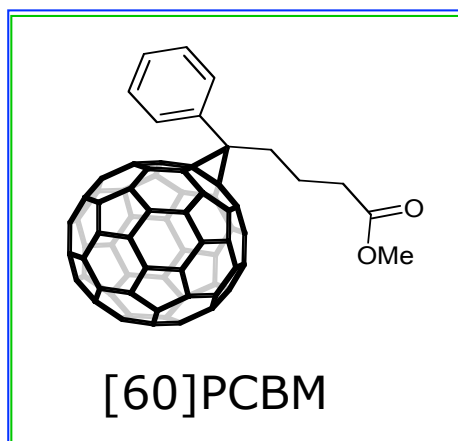


Some typical electron *acceptor* molecules

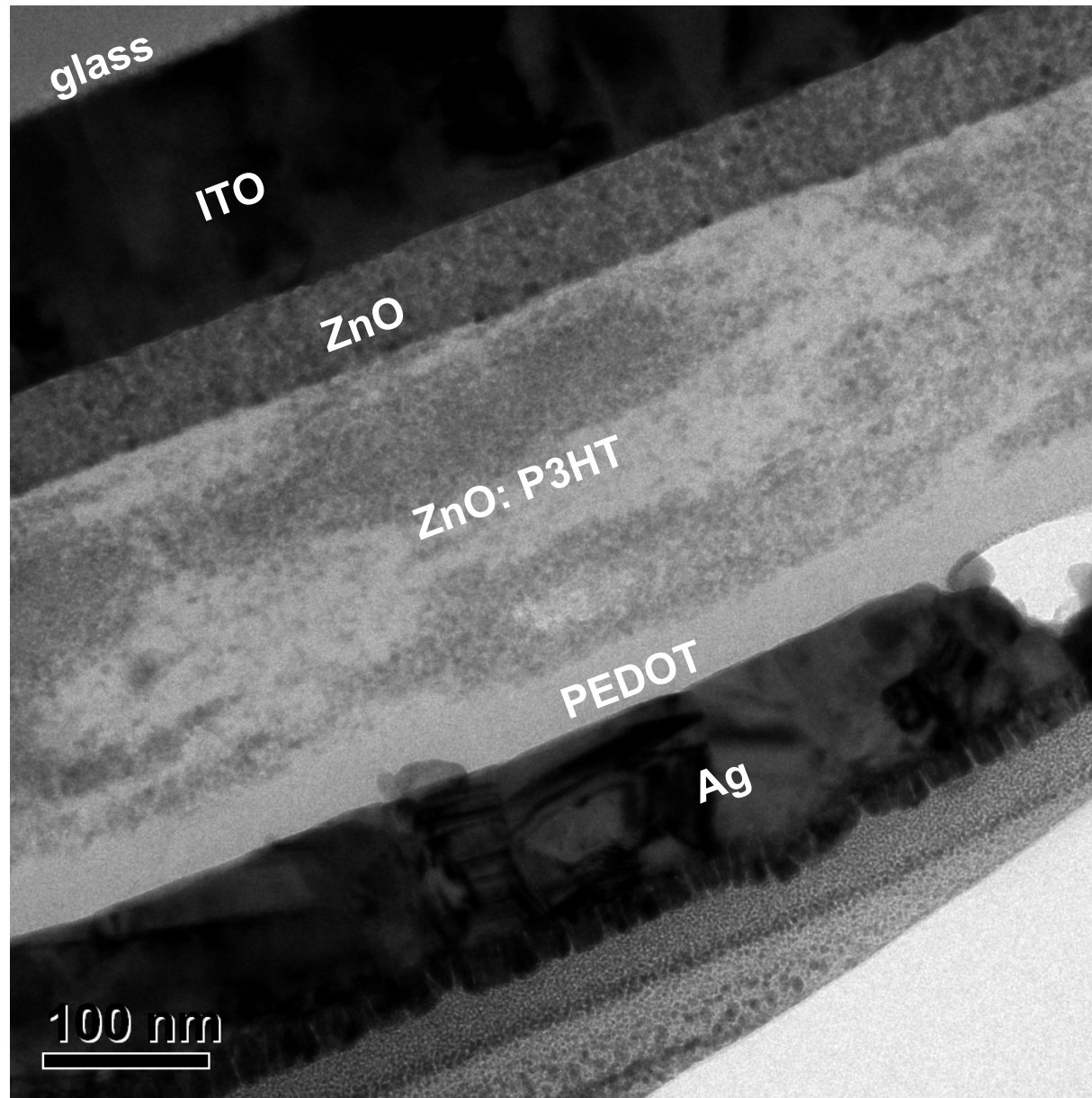
small molecules - require vacuum deposition



solution processable small molecules



Cross-sectional image of a representative device



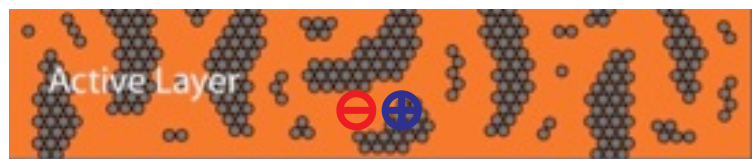
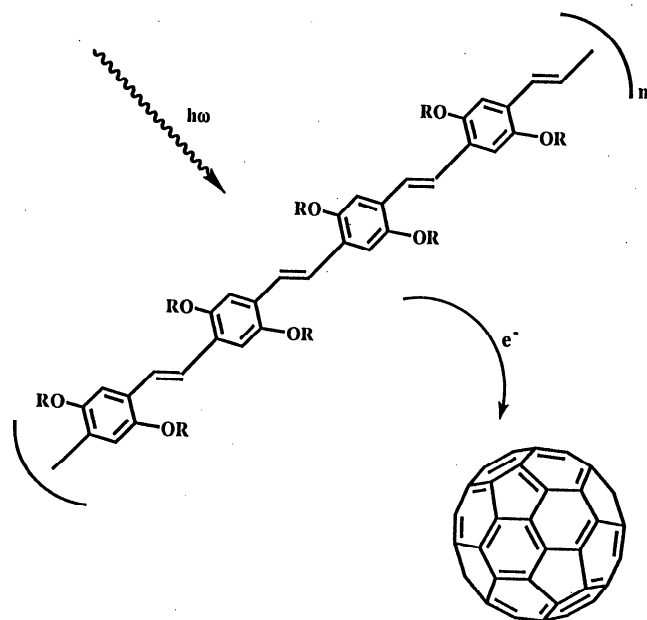
Julia Hsu, UT Dallas

Basic operation of a bulk heterojunction OPV

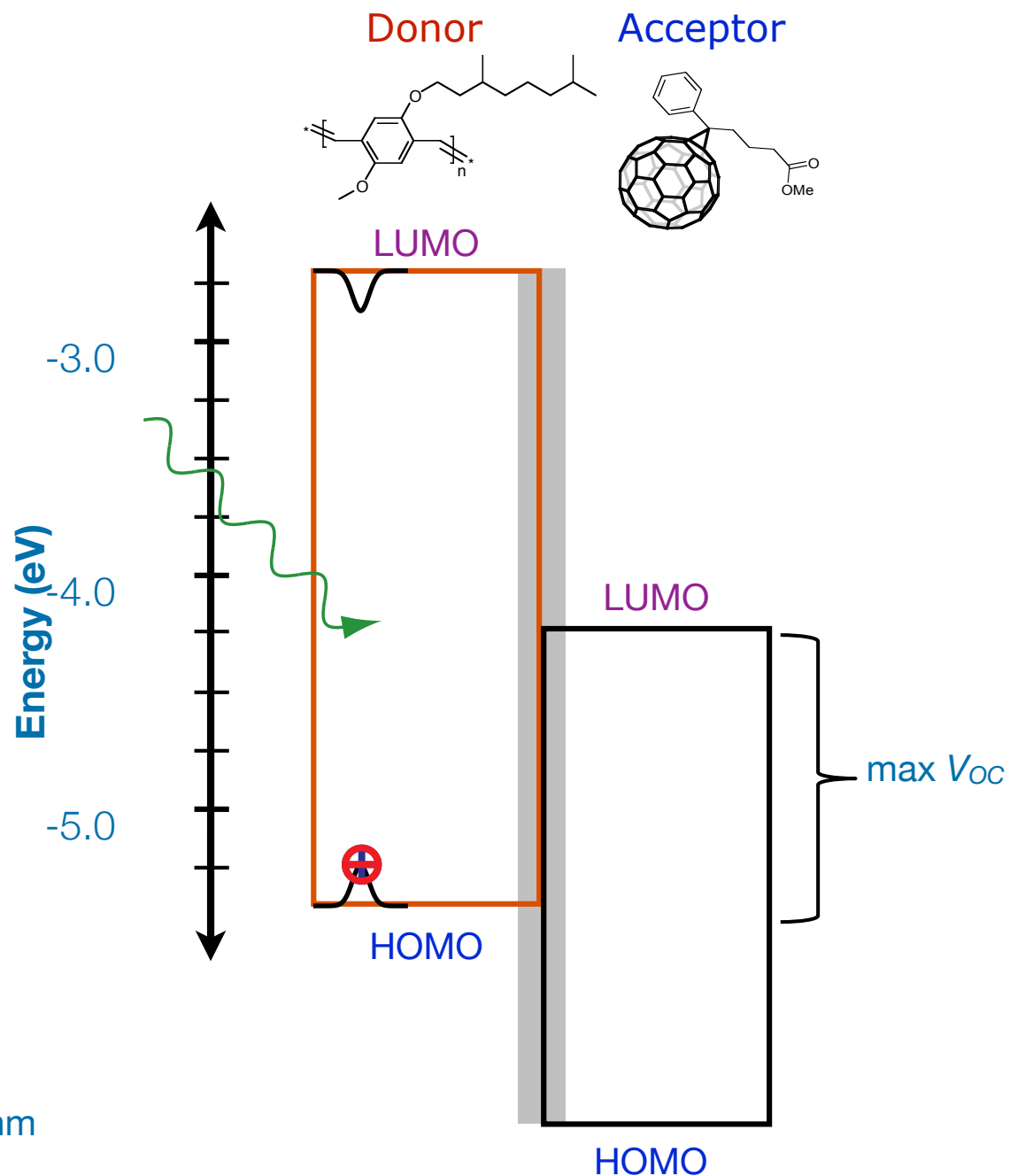
Ultrafast photo-induced electron transfer

Forward rate ~ 45 fs

Backward rate $\sim 1\mu$ s



100-200 nm

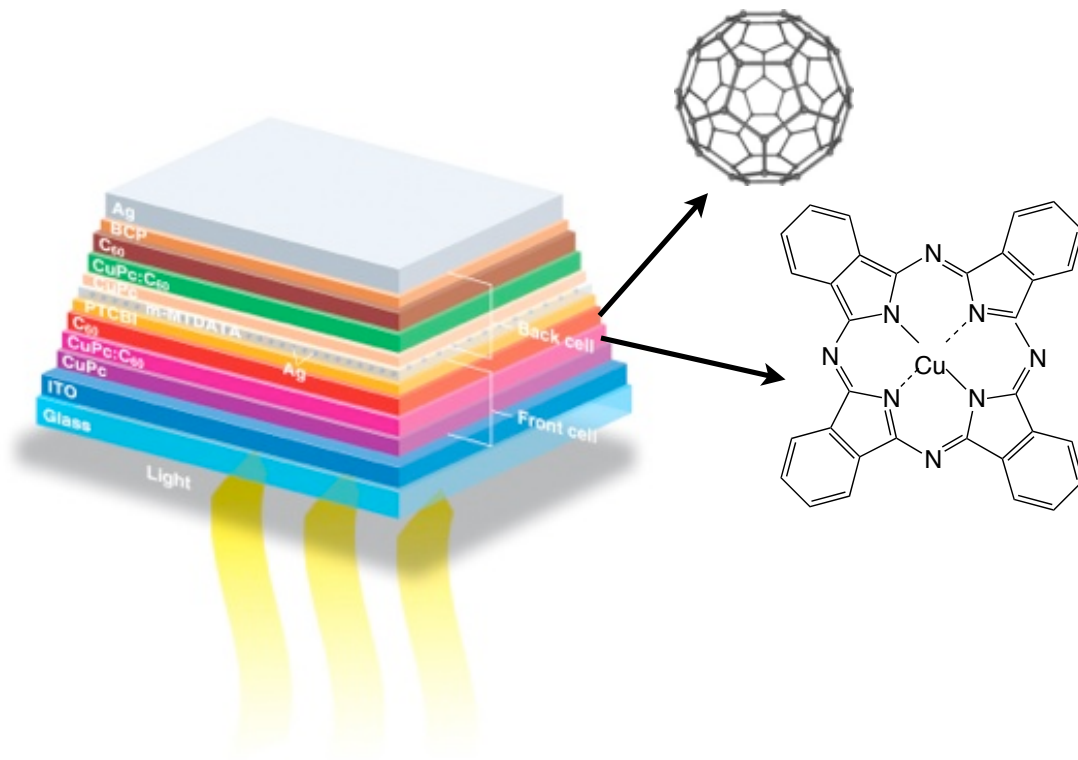
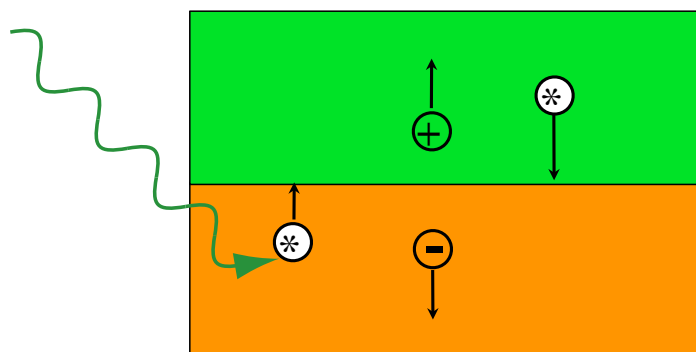


LUMO = Lowest Unoccupied Molecular Orbital / Conduction band
HOMO = Highest Occupied Molecular Orbital / Valence band

Planar versus bulk donor-acceptor heterojunctions

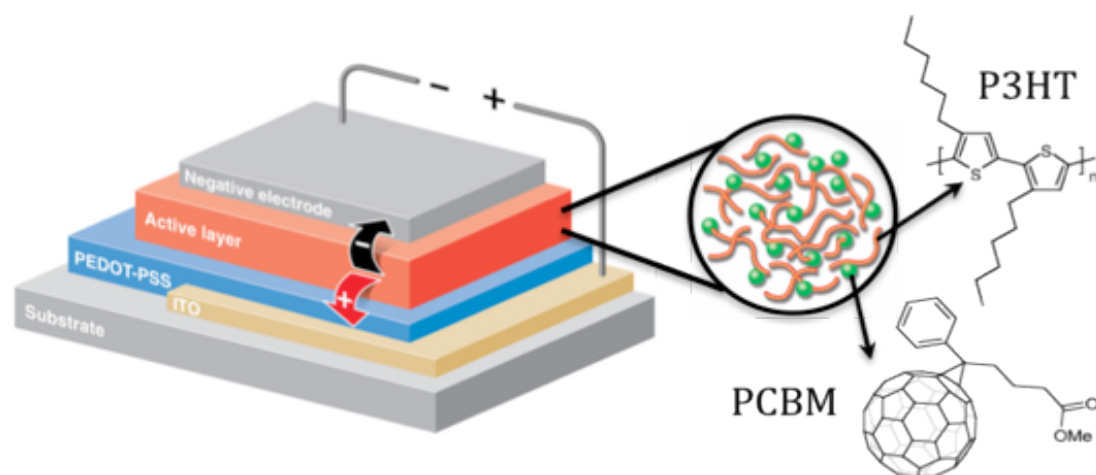
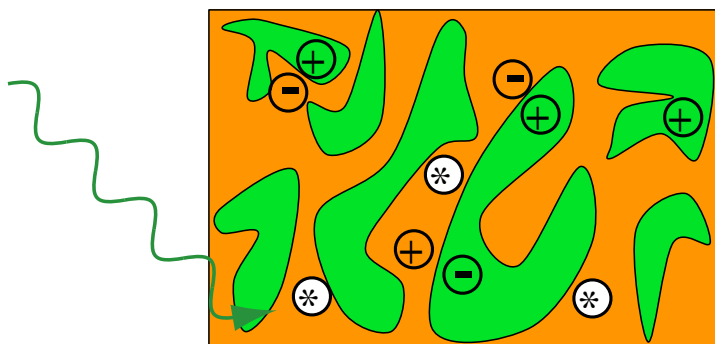
Planar heterojunction

- exciton must diffuse a long distance
- carrier recombination is mitigated

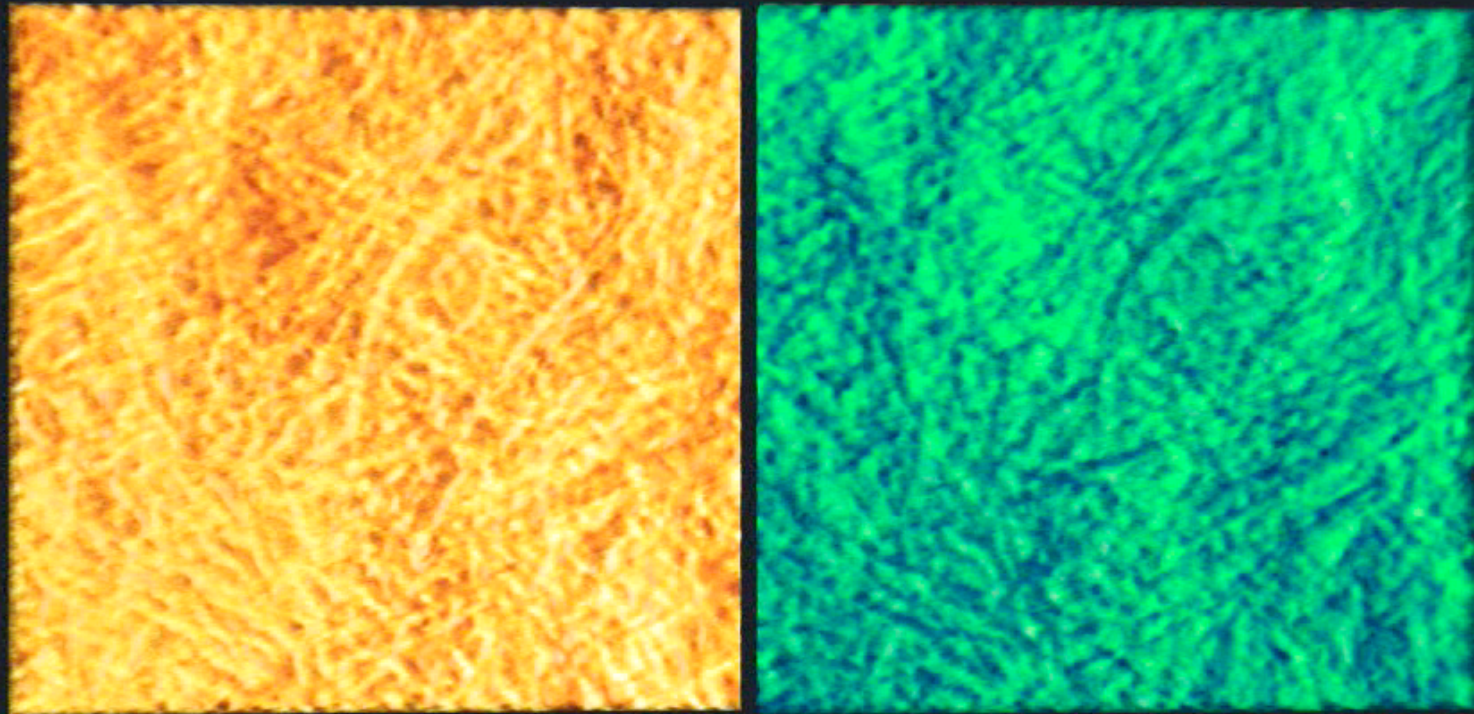


Bulk heterojunction

- exciton is easily dissociated
- carrier recombination is enhanced



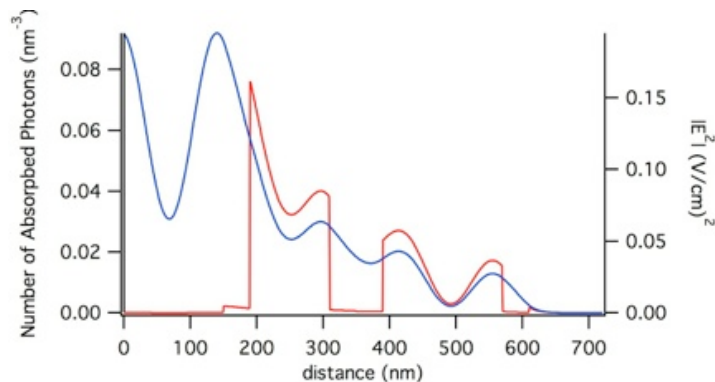
Low Loss EF-TEM
P3HT:PCBM



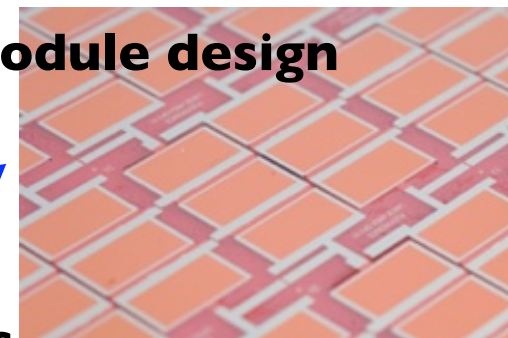
(800 nm field of view)

Dr. Andrew Herzing
Dr. Dean DeLongchamp
NIST OPV Project

OPV is inherently multi-scale

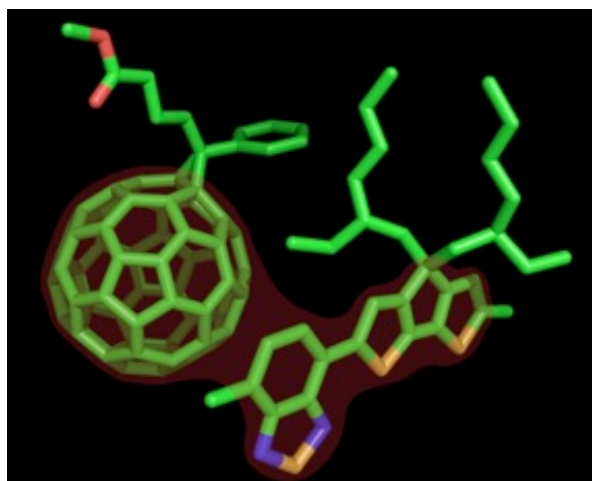


Module design

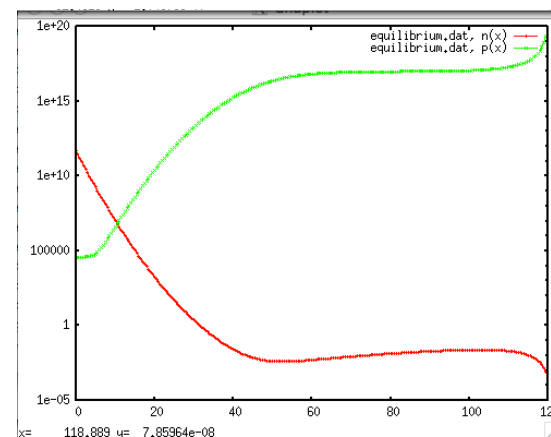


**Optical considerations
and light management**

(Plextronics)

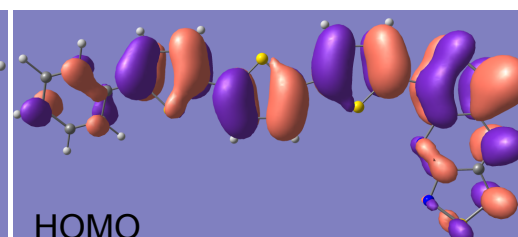
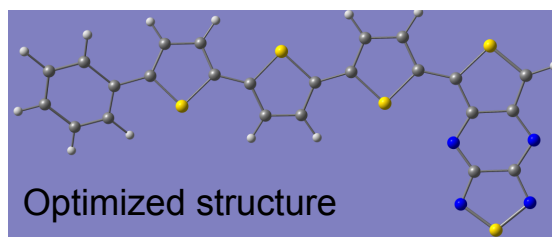


**Device
physics**



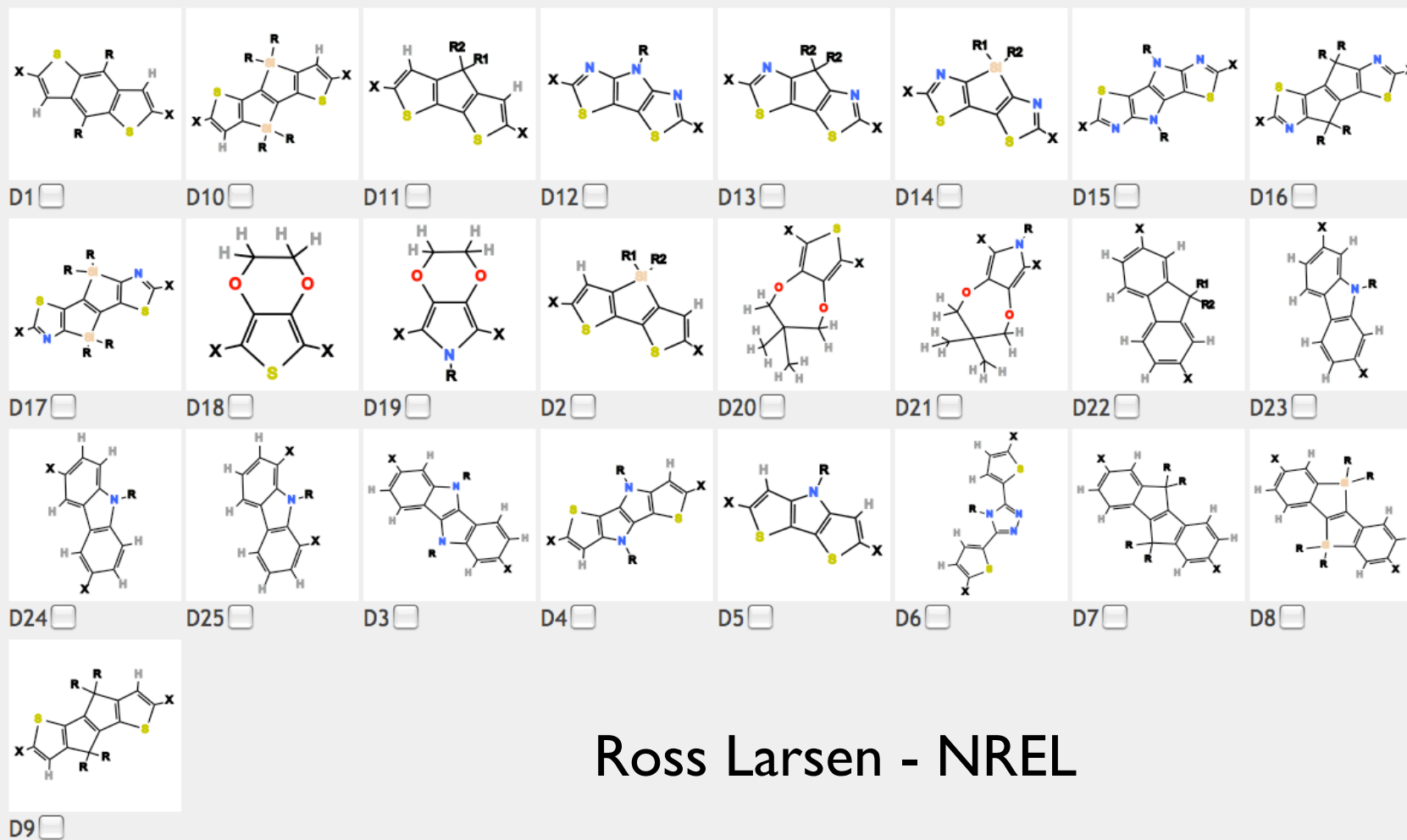
**Photophysics and
charge transport**

Molecular design



Examples from donor library

Donors



Ross Larsen - NREL

DFT/TD-DFT applied to these for calculating band gap and HOMO/LUMO energies

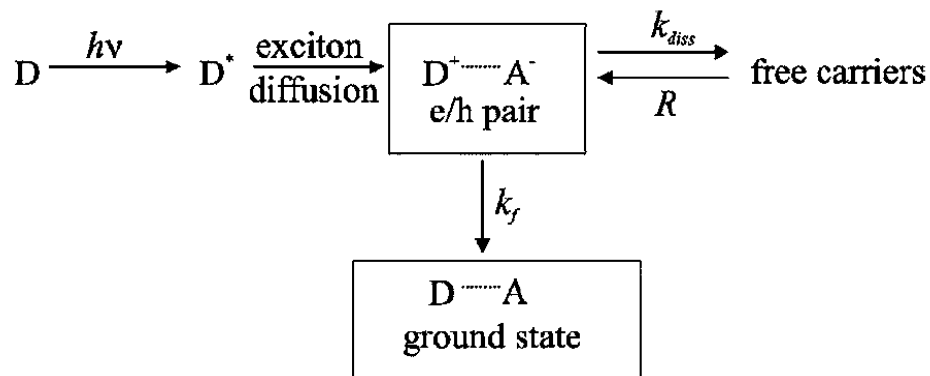
Other efforts: Harvard Clean Energy Project (Aspuru-Guzik)
University of Pittsburgh (Hutchinson)

I-D steady-state drift-diffusion model

Poisson Equation :

$$\frac{\partial^2}{\partial x^2} \psi(x) = \frac{e}{\epsilon} (n(x) - p(x) - C(x))$$

Intrinsic, dark carriers



$$U = PG - (1 - P)R$$

$$R = \gamma(np - n_i^2)$$

$$P = \frac{k_d}{k_d + k_f}$$

$$k_d = k_d(x, T, E, E_b)$$

$$k_f = \text{parameter}$$

Continuity Equations :

$$\frac{\partial}{\partial x} J_n(x) = eU(x)$$

$$\frac{\partial}{\partial x} J_p(x) = -eU(x)$$

$$J_n = enE + D_n \frac{\partial}{\partial x} n$$

$$D_n = \mu_n k_B T / e$$

$$J_p = epE - D_p \frac{\partial}{\partial x} p$$

$$D_p = \mu_p k_B T / e$$

$$E = -\frac{\partial}{\partial x} \psi$$

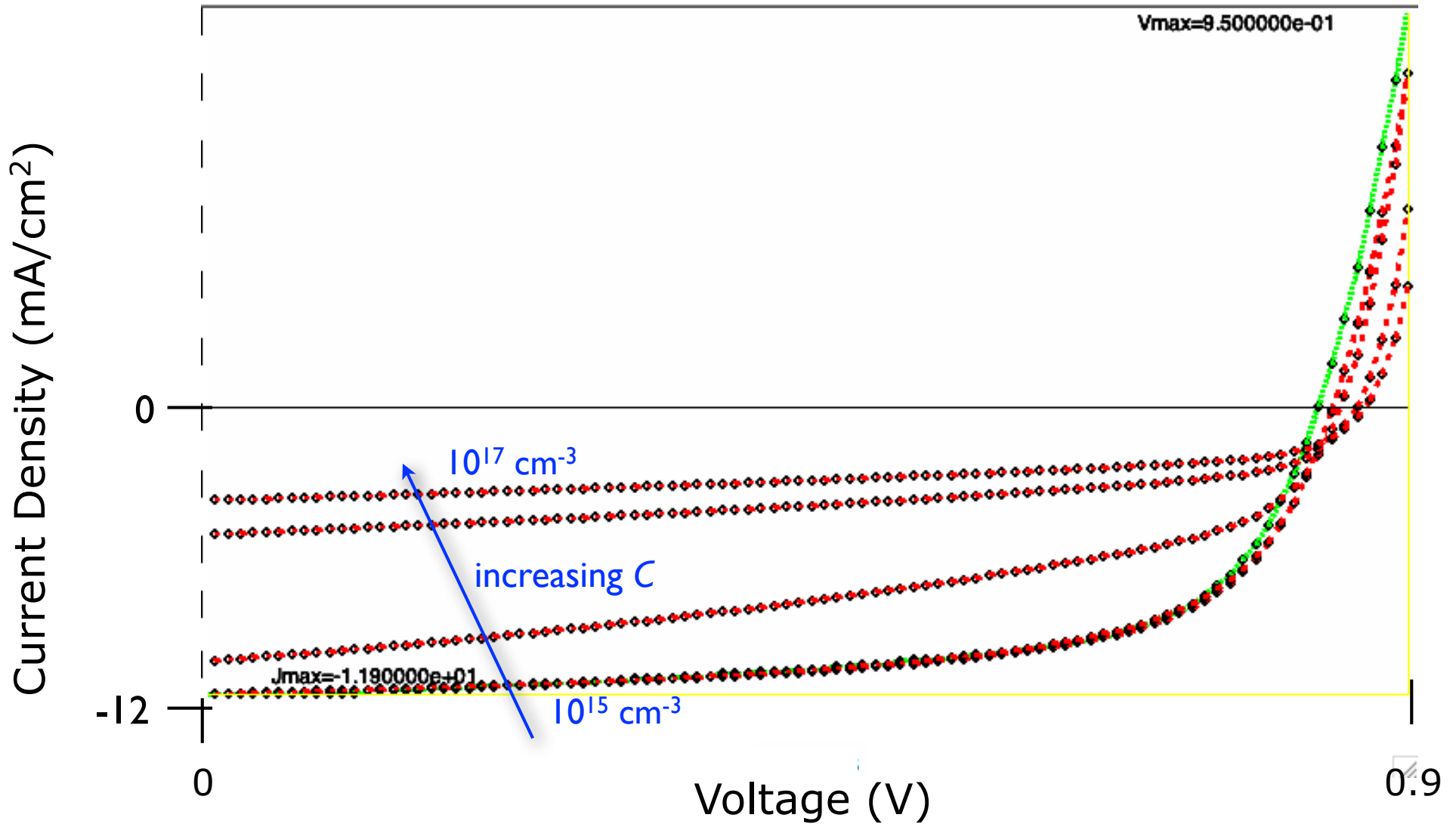
$$U = \text{net generation rate}$$

Koster, et al., *Phys. Rev. B* **72** 085205 (2005)

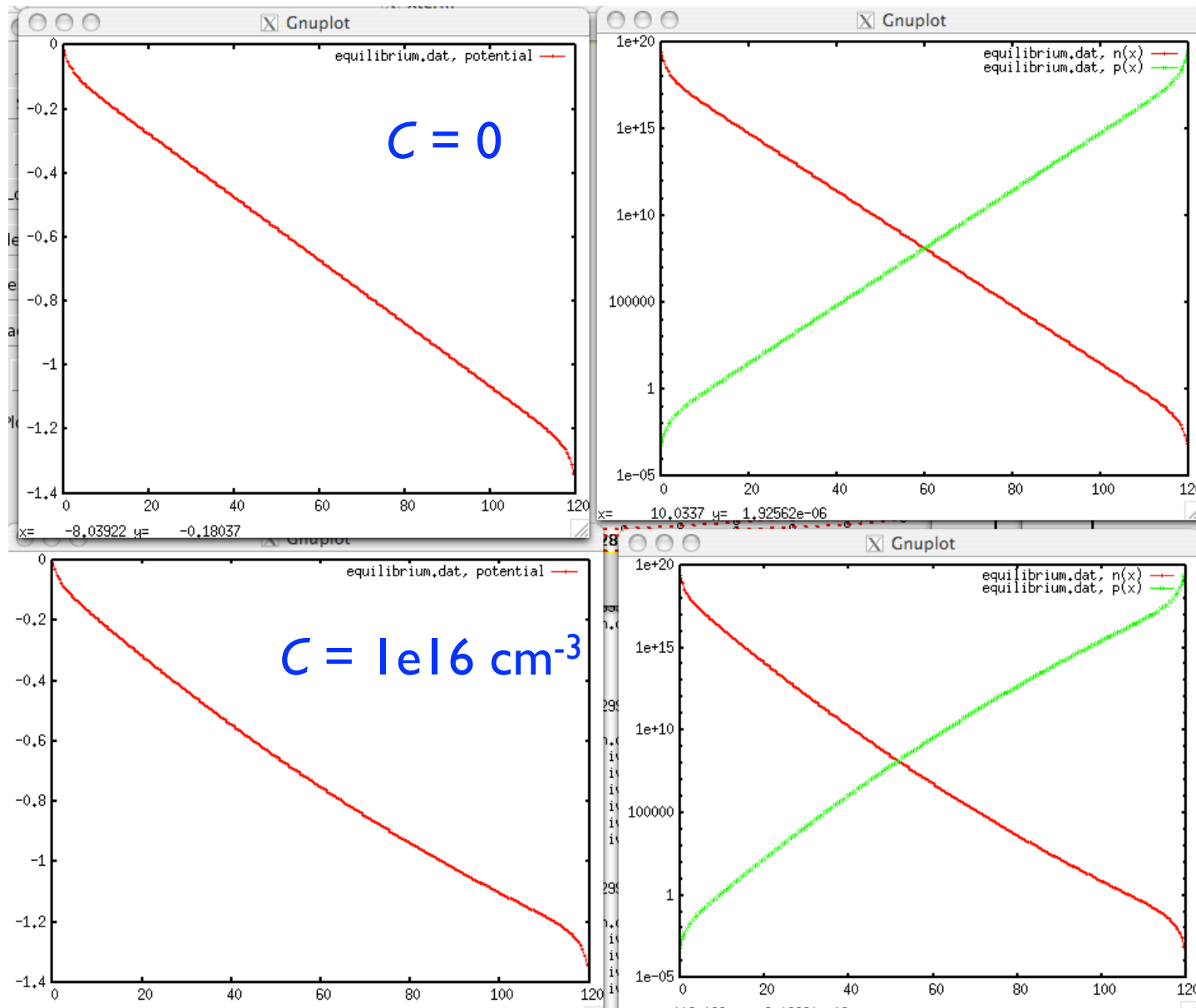
- BHJ + ideal (ohmic) contacts, no other layers (e.g. PEDOT:PSS)
- Bulk heterojunction transport parameterized by $\mu_{n,p}$, K_f

Software (Python) implementation performed by *Peter Graf*,
NREL Scientific Computing Center

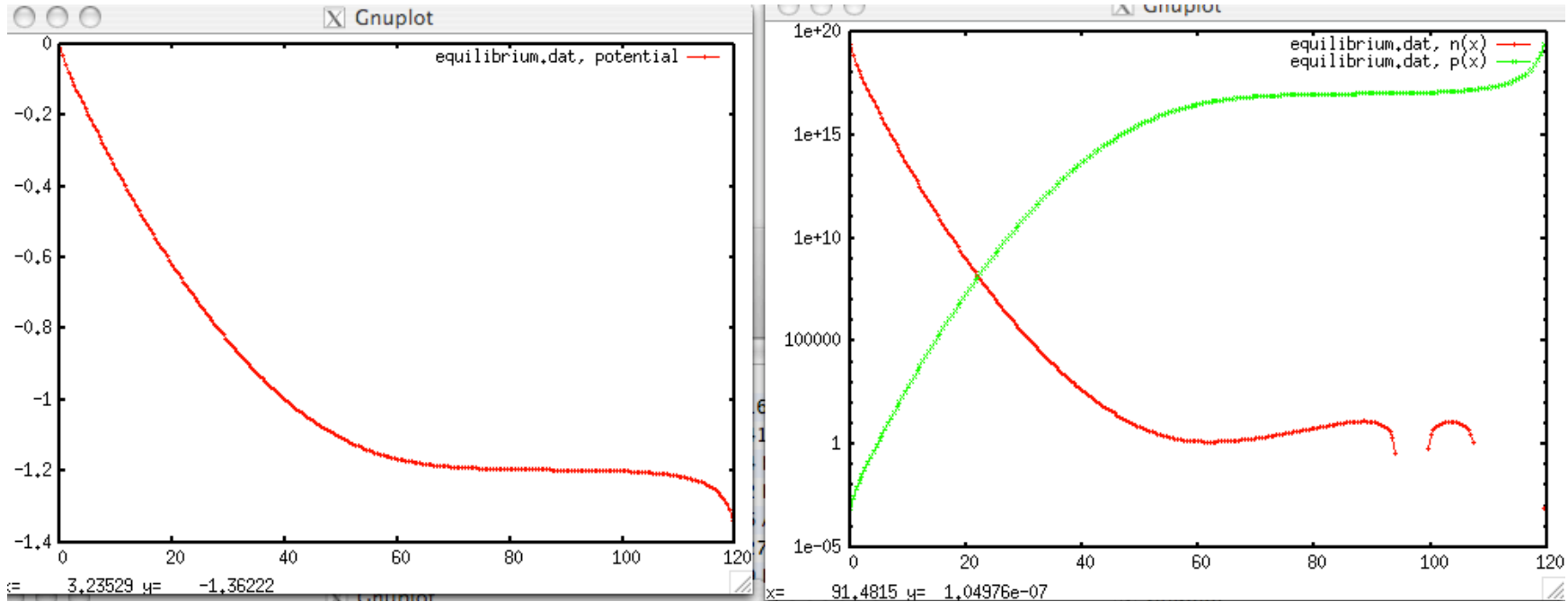
Simulation of the impact of dark carrier density (C) on JV curves.



Simulation of the impact of dark carrier density (C) on the electric potential and carrier distributions.



$$C = 1e17 \text{ cm}^{-3}$$

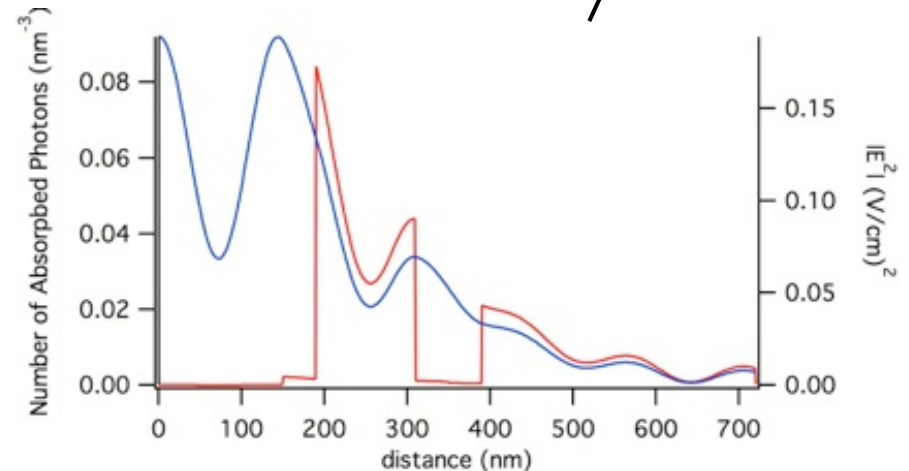
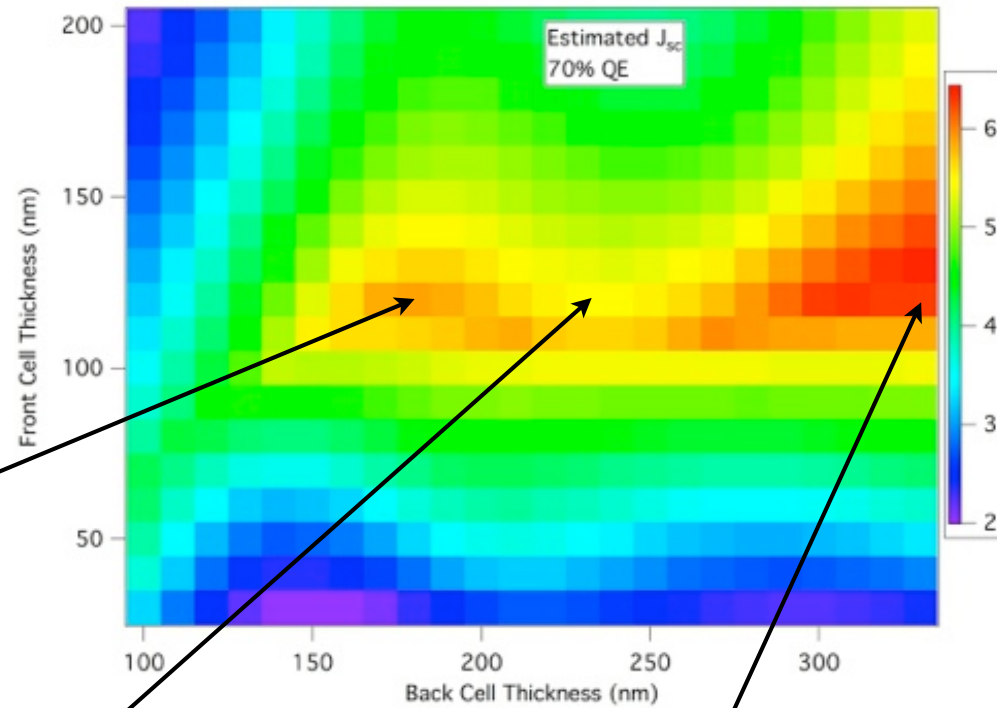
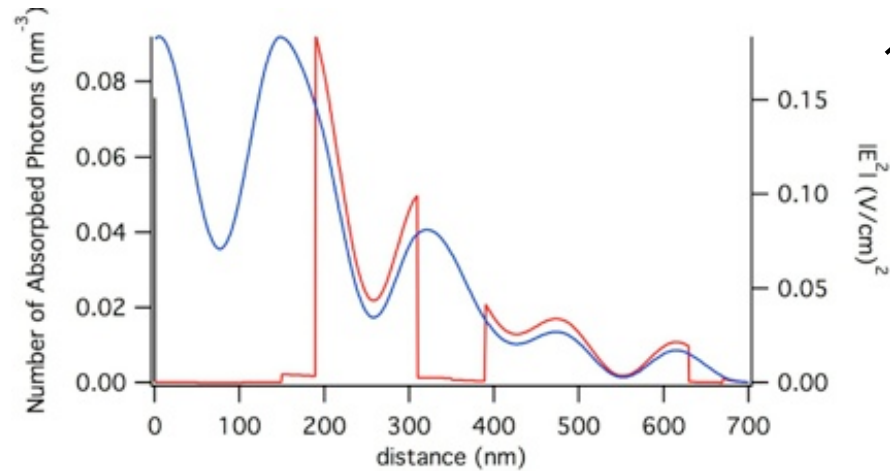
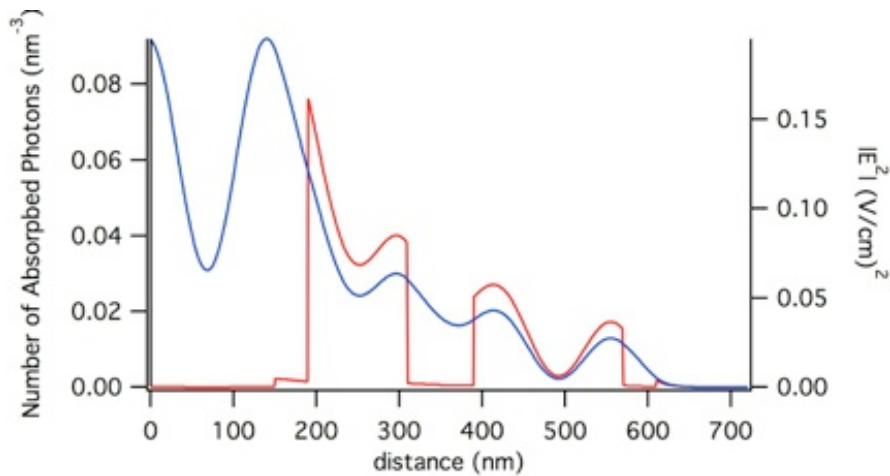


Experiment*: P3HT Na = $5e16 \text{ cm}^{-3}$

*Ziqi Liang, Alexandre Nardes, Dong Wang, Joseph J. Berry, and Brian A. Gregg, "Defect Engineering in pi-Conjugated Polymers", *Chem. Mater.* 2009, **21**, 4914–4919.

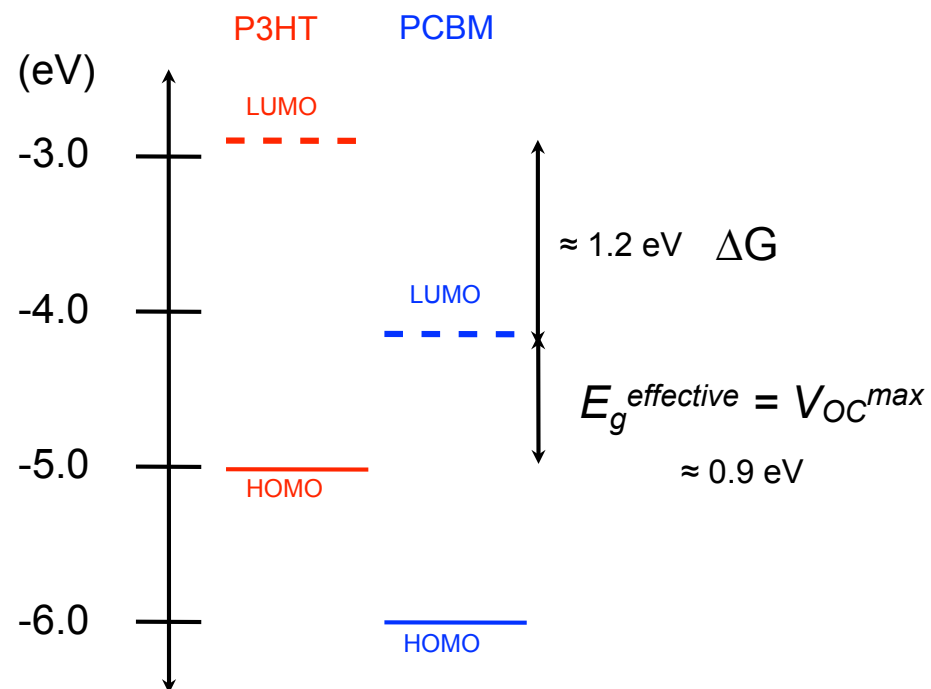
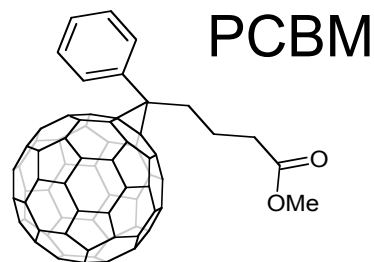
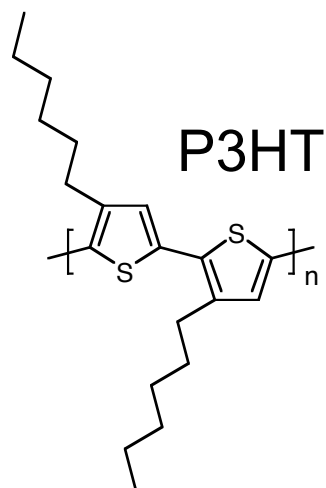
Modeling of optical field strength in tandem devices

Transfer matrix calculations of optical field strength and resulting device current:



Calculations courtesy Brian Bailey and Sarah Cowan, NREL.

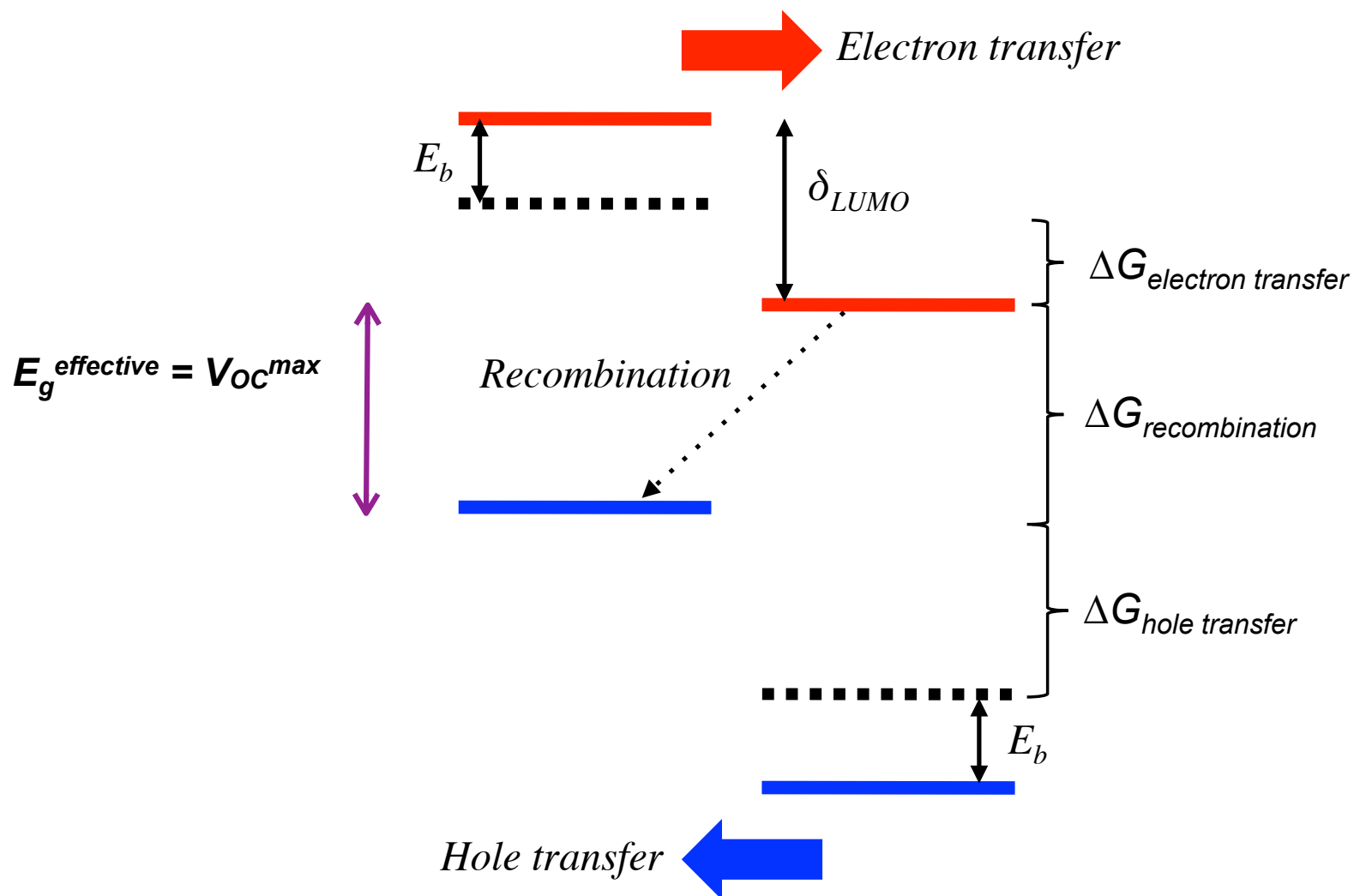
The LUMO-LUMO (δ_{LUMO}) band offset is typically very large



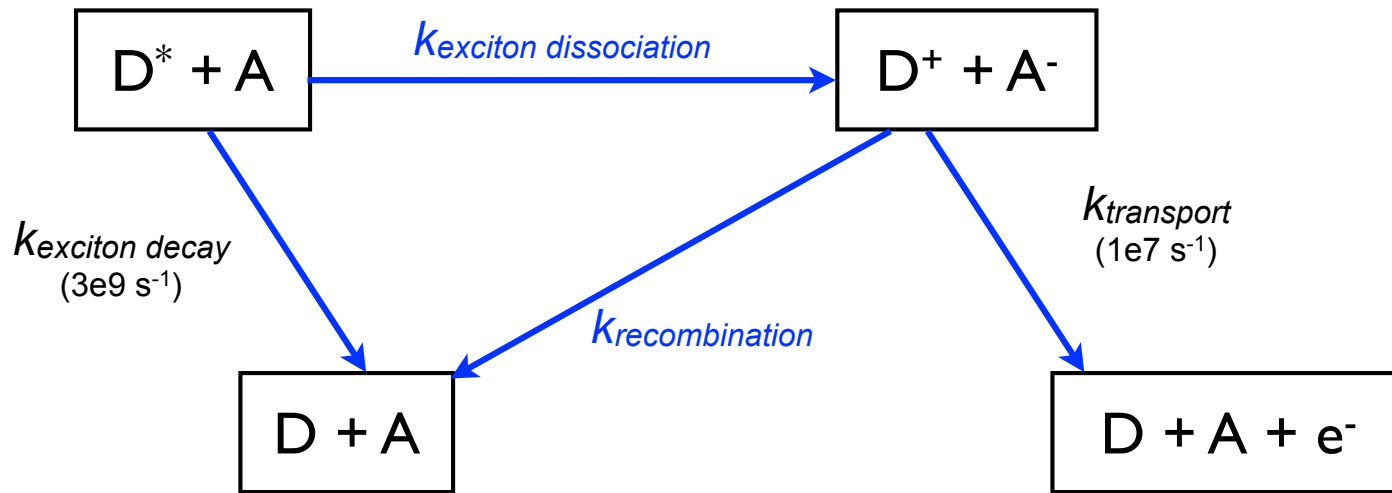
Open Question:

Is the thermal energy gained from a large band offset necessary for efficient charge separation?

A more complete picture



Simplified kinetic scheme for photocurrent production:



(and analogously for excitation of the *acceptor*)

Assume *dissociation* and *recombination* governed by Marcus theory:

$$k = \left(\frac{4\pi^2}{h} \right) V^2 \left(\frac{1}{\sqrt{4\pi\lambda k_B T}} \right) \exp \left(\frac{-(\Delta G + \lambda)^2}{4\lambda k T} \right)$$

$\sim 0.01 \text{ eV}$
 ΔG is negative

An example, high performance OPV system

Y. Liang et al, *Adv. Mater.* **22**, E135-E138 (2010).

For the Bright Future—Bulk Heterojunction Polymer Solar Cells with Power Conversion Efficiency of 7.4%

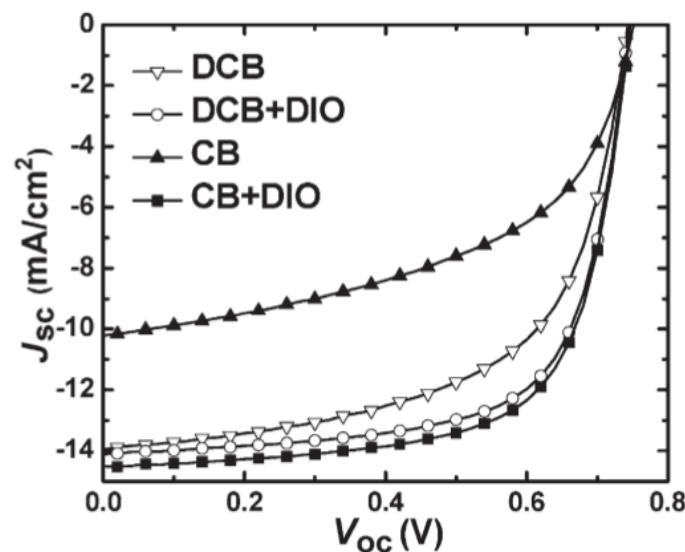
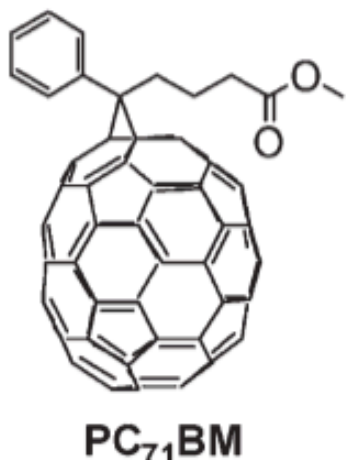
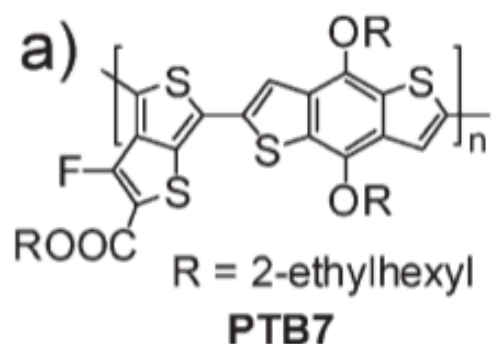


Figure 2. J - V curves of PTB7/PC₇₁BM devices using (i) DCB only, (ii) DCB with 3% DIO, (iii) CB, and (iv) CB with 3% DIO as solvents.

| | V_{oc} [V] | J_{sc} [mA cm ⁻²] | FF [%] | PCE [%] | J_{sc} (calc.) [mA cm ⁻²] | Error [%] |
|---------|-----------------|------------------------------------|-----------|------------|--|--------------|
| DCB | 0.74 | 13.95 | 60.25 | 6.22 | | |
| DCB+DIO | 0.74 | 14.09 | 68.85 | 7.18 | 13.99 | 0.74 |
| CB | 0.76 | 10.20 | 50.52 | 3.92 | | |
| CB+DIO | 0.74 | 14.50 | 68.97 | 7.40 | 14.16 | 2.34 |

Pathway to higher efficiency: Reducing λ

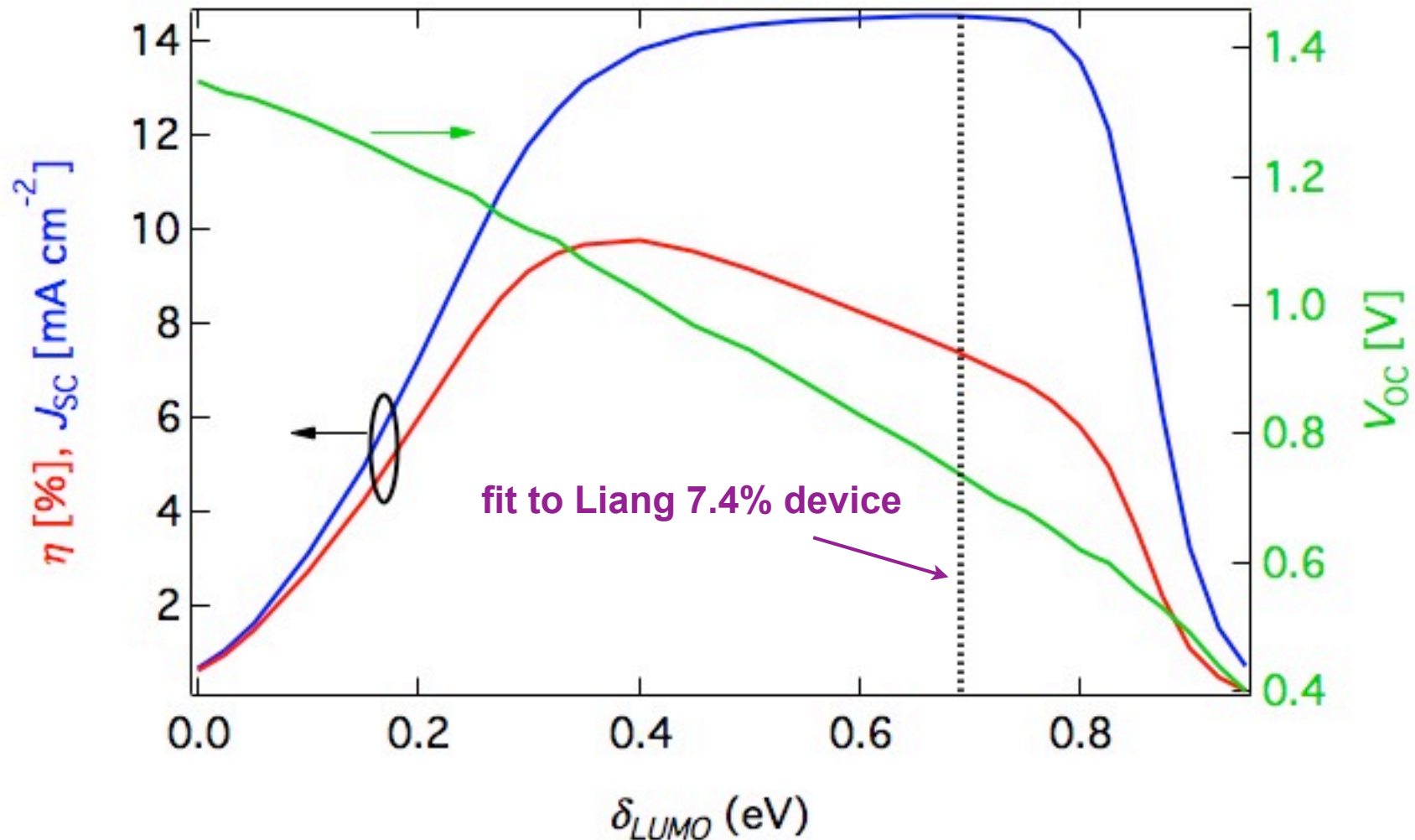
High reorganization energy regime: $\lambda = 0.75$ eV

Model parameters:

$E_{gap}(\text{PTB7}) = 1.64$ eV
peak OD (PTB7) = 0.51

$E_{gap}([\text{70}]\text{PCBM}) = 1.73$ eV
peak OD ([70]PCBM) = 0.33

$\lambda_{\text{electron transfer}} = \lambda_{\text{hole transfer}} = 0.75$ eV



Pathway to higher efficiency: Reducing λ

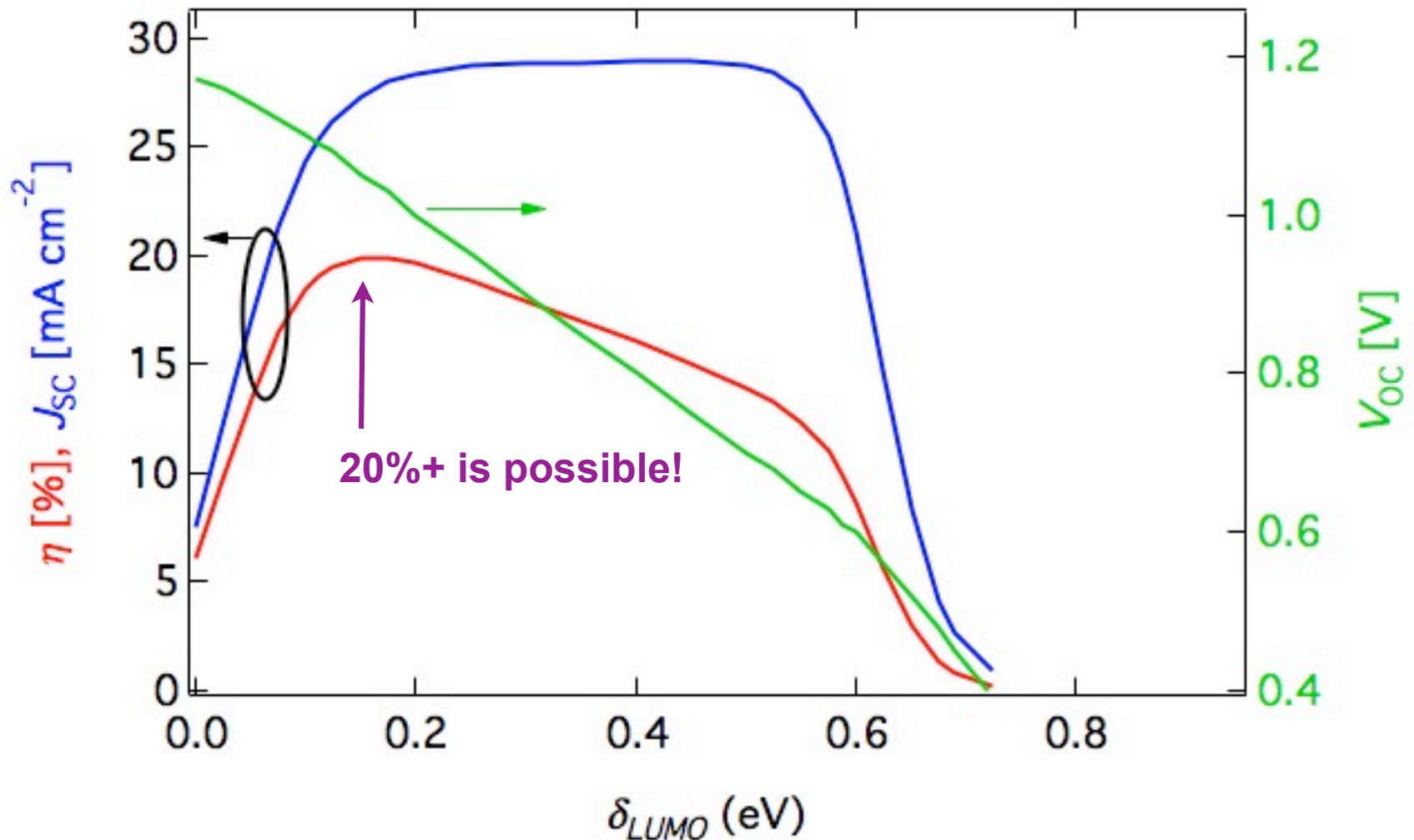
Highly optimized regime: $\lambda = 0.30$ eV and high optical density

Model parameters:

$E_{gap}(\text{PTB7}) = 1.40$ eV
peak OD (PTB7) = 1.00

$E_{gap}([\text{70}]\text{PCBM}) = 1.40$ eV
peak OD ([70]PCBM) = 1.00

$\lambda_{electron\ transfer} = \lambda_{hole\ transfer} = 0.30$ eV



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NATURAL SCIENCES & MATHEMATICS

Graduate students

- Xin Jiang - co-advised by Nikos Kopidakis, NREL
- Brian Appleby - co-advised by Nikos Kopidakis, NREL
- Alex Dixon - co-advised by Nikos Kopidakis, NREL
- Ajaya Sigdel - advised by Joseph Berry, NREL
- Daniel Weingarten - co-advised by Dan Dessau, CU Boulder



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Chemical and Materials Sciences

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Klara Maturova
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Obadiah Reid
Andrew Ferguson
Jeff Blackburn
Jao van de Lagemaat
Brian Gregg
Garry Rumbles

Scientific Computing Center

Ross Larsen
Peter Graf
Steve Hammond



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Scialog Program

Contact:
sean.shaheen@du.edu